TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MBL3245BFT, TC7MBL3245BFK

Octal Low Voltage Bus Switch

The TC7MBL3245B provides eight bits of low-voltage, high-speed bus switching in a standard '245 device pinout. The low ON-resistance of the switch allows connections to be made with minimal propagation delay and while maintaining CMOS low power dissipation.

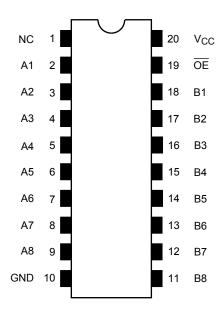
The device comprises a single 8-bit switch. When output enable (\overline{OE}) is low, the switch is on and port A is connected to port B. When \overline{OE} is high, the switch is open and a high-impedance state exists between the two ports.

All inputs are equipped with protection circuits to guard against static discharge.

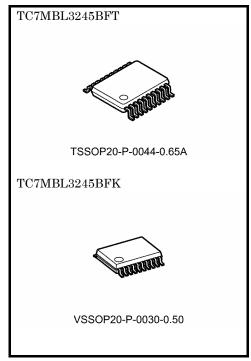
Features

- Operating voltage: $V_{CC} = 1.65 \sim 3.6 \text{ V}$
- Low capacitance: CI/O=19pF Switch On (typ.) @3V
- Low ON-resistance: $R_{ON} = 4 \Omega \text{ (typ.) } @3V$
- ESD performance: Machine model $\geq \pm 200 \text{ V}$ Human body model $\geq \pm 2000 \text{ V}$
- Power-down protection for inputs (OE input only)
- Package: TSSOP20,VSSOP (US20)
- Pin compatible with the 74xx245 type

Pin Assignment (top view)



NC-No Internal Connection



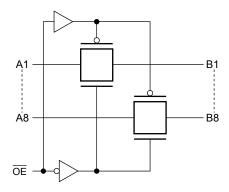
Weight:

TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Truth Table

Inputs	Function			
ŌĒ	- Tunction			
L	A port = B port			
Н	Disconnect			

System Diagram



Absolute Maximum Ratings (Note)

Charac	cteristic	Symbol	Rating	Unit
Power supply rang	е	V _{CC}	-0.5~4.6	V
Control pin input ve	oltage	V _{IN}	-0.5~4.6	V
Switch terminal I/O voltage		VS	-0.5~Vcc+0.5	V
Clump diode current	Control input pin	luz	-50	mA
	Switch terminal	lik	±50	IIIA
Switch I/O current		IS	128	mA
Power dissipation		PD	180	mW
DC V _{CC} /GND current		I _{CC} /I _{GND}	±100	mA
Storage temperatu	re	T _{stg}	-65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristic	Symbol	Rating	Unit
Power supply voltage	V _{CC}	1.65~3.6	٧
Control pin input voltage	V _{IN}	0~3.6	٧
Switch I/O voltage	VS	0~Vcc	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
	- J	1000 0011411011	V _{CC} (V)		. yp.	111421	O
High-level control input voltage	V_{IH}	_	1.65 to 3.6	0.7 × V _{CC}	_	_	V
Low-level control input voltage	V _{IL}	-	1.65 to 3.6	_	_	0.3 × V _{CC}	V
Control input current	I _{IN}	V _{IN} = 0 to 3.6 V	1.65 to 3.6	_	_	±1.0	μА
Power off leakage current	loff	OE = 0 to 3.6 V	0	_	_	1.0	μА
Off-stage leakage current (switch off)	I _{SZ}	A, B = 0 to V_{CC} , $\overline{OE} = V_{CC}$	1.65 to 3.6	_	_	±1.0	μΑ
		$V_{IS} = 0 \text{ V}, I_{IS} = 30 \text{ mA}$ (Note) 3.0	_	4	7	
		$V_{IS} = 3.0 \text{ V}, I_{IS} = 30 \text{ mA}$ (Note) 3.0	_	6	9	
Switch ON-resistance	D	$V_{IS} = 2.4 \text{ V}, I_{IS} = 15 \text{ mA}$ (Note) 3.0	_	7	12	Ω
(Note 2)	R _{ON}	$V_{IS} = 0 \text{ V}, I_{IS} = 24 \text{ mA}$ (Note) 2.3	_	4	8	22
		$V_{IS} = 2.3 \text{ V}, I_{IS} = 24 \text{ mA}$ (Note) 2.3	_	7	11	
		$V_{IS} = 2.0 \text{ V}, I_{IS} = 24 \text{ mA}$ (Note) 2.3	_	8	13	
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND, I _{OUT} = 0	3.6	_	_	10	μА

Note 1: All typical values are at $Ta = 25^{\circ}C$.

Note 2: Measured by voltage drop between A and B pins at indicated current through the switch. ON-resistance is determined by the lower of the voltages on the two pins (A or B).

AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

01	0	Took Condition				1114
Characteristic	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
	^t pZL ^t pZH	Figure 1, Figure 2	3.3 ± 0.3	_	6	ns
Output enable time			2.5 ± 0.2	_	7	
			1.8 ± 0.15	_	11	
	t _{pLZ} t _{pHZ}	Figure 1, Figure 2	3.3 ± 0.3		6	
Output disable time			2.5 ± 0.2		7	ns
	p		1.8 ± 0.15		11	

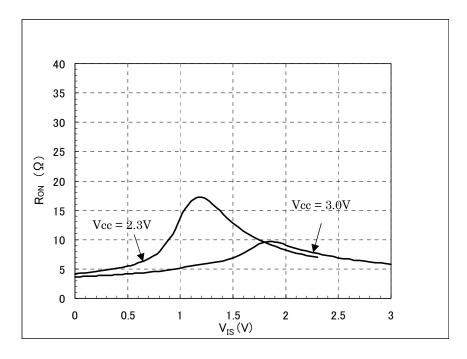
Capacitive Characteristics (Ta = 25°C)

Characteristic (Note)	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Control input capacitance	C _{IN}		3.0	3	pF
Cuitab terminal agnesitance	Cur	OE = V _{CC} Switch Off	3.0	9	pF
Switch terminal capacitance	C _{I/O}	OE = GND Switch On	3.0	19	pF

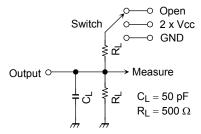
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Note: This parameter is guaranteed by design.

$R_{ON} - V_{IN}$ Characteristic Curves (Typ.), $Ta = 25^{\circ}C$



AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t_{pLZ} , t_{pZL}	$2\times V_{CC}$
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveforms

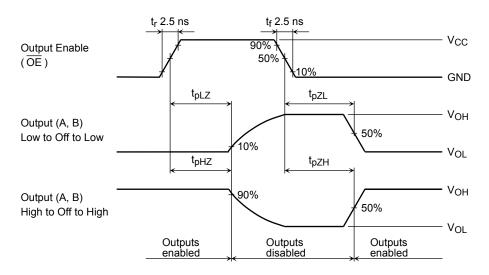


Figure 2 t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

Rise and Fall Times (tr / tf) of the TC7MBL3245B I/O Signals

The tr(out) and tf(out) values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance ($C_{I/O}$) and the on-resistance (R_{ON}) of the input.

In practice, the tr(out) and tf(out) values are also affected by the circuit's capacitance and resistance components other than those of the TC7MBL3245B.

The tr / tf (out) values can be approximated as follows. (Figure 4 shows the test circuit.)

$$tr / tf out (approx) = -(C_{I/O} + C_L) \cdot (R_{DRIVE+} R_{ON}) \cdot ln (((V_{OH} - V_{OL}) - V_M) / (V_{OH} - V_{OL}))$$

where, RDRIVE is the output impedance of the previous-stage circuit.

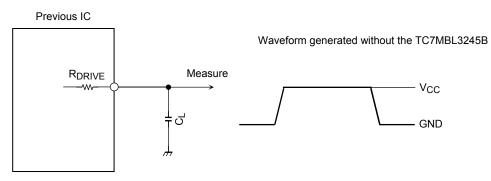
Calculation example:

tr out (approx) = - (19+ 15)E-12 · (120 + 4) ·
$$\ln (((3.0 - 0) - 1.5)/(3.0 - 0))$$

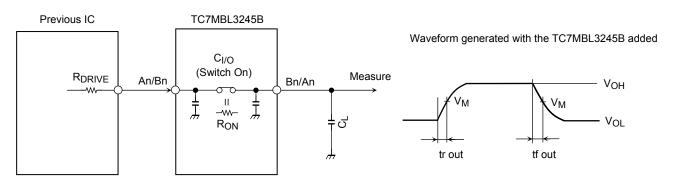
 $\approx 3.0 \text{ns}$

Calculation conditions:

 V_{CC} = 3.0V , C_L = 15pF , R_{DRIVE} = 120 Ω (output impedance of the previous IC), V_M = 1.5V(V_{CC} / 2) Output of the previous IC = digital (i.e., high-level voltage = V_{CC} ; low-level voltage = GND)



R_{DRIVE} = output impedance of the previous IC



R_{DRIVE} = output impedance of the previous IC

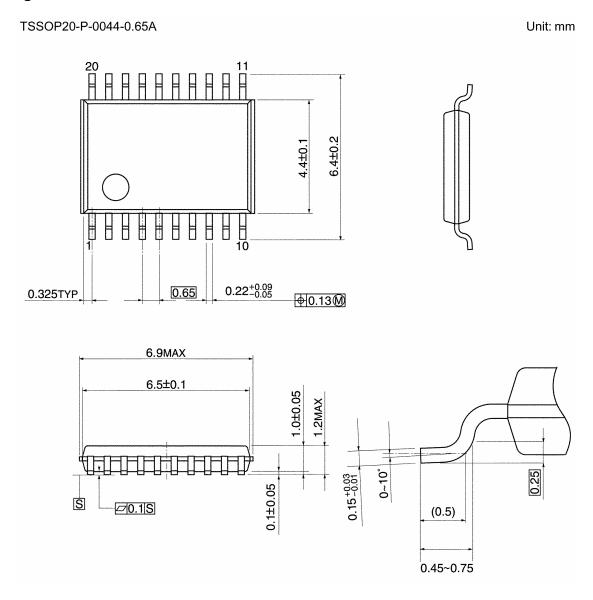
Parameter	Vcc						
Farameter	3.3 ± 0.3 V	2.5 ± 0.2 V	1.8 ± 0.15 V				
V_{M}	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2				

Figure 3 Test Circuit

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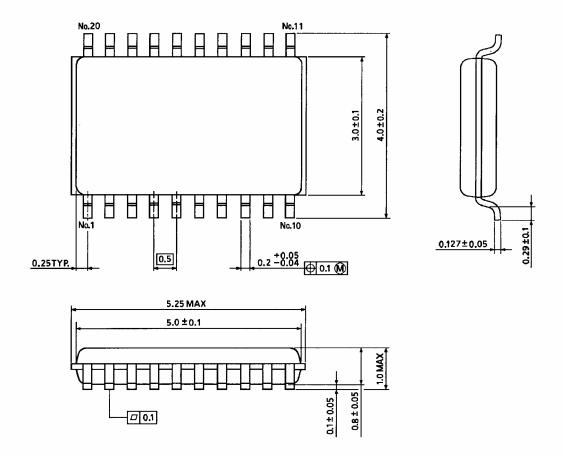
Package Dimensions



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Weight: 0.08 g (typ.)

Package Dimensions



Weight: 0.03 g (typ.)

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